NPN VHF/UHF Transistor

The MMBTH10M3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose VHF/UHF applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

Features

- Reduces Board Space
- This is a Halide–Free Device
- This is a Pb–Free Device

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	25	Vdc
Collector – Base Voltage	V _{CBO}	30	Vdc
Emitter – Base Voltage	V_{EBO}	3.0	Vdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	PD	265 2.1	m₩ mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

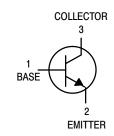
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

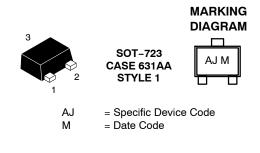
2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



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ORDERING INFORMATION

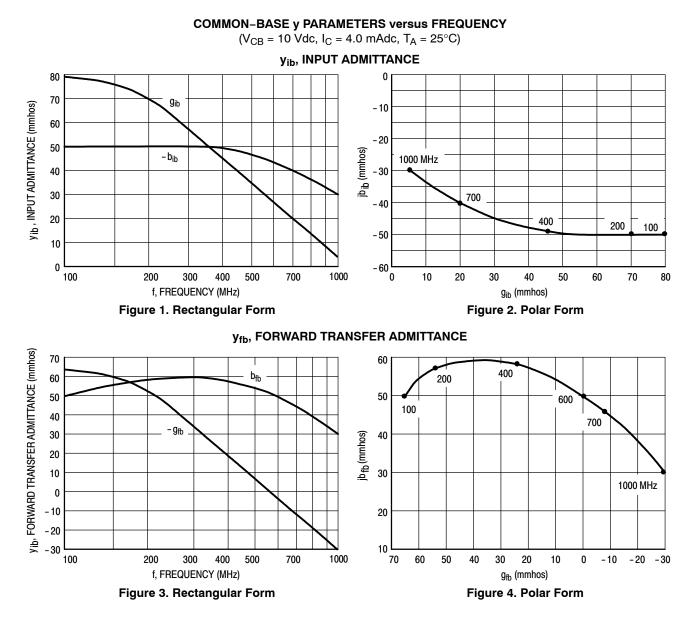
Device	Package	Shipping [†]	
MMBTH10M3T5G	SOT-723 (Pb-Free)	8000/Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	25	-	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	30	-	-	Vdc
Emitter-Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	3.0	-	-	Vdc
Collector Cutoff Current ($V_{CB} = 25 \text{ Vdc}, I_E = 0$)	I _{CBO}	-	-	100	nAdc
Emitter Cutoff Current ($V_{EB} = 2.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	-	100	nAdc
ON CHARACTERISTICS					1
DC Current Gain (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	h _{FE}	60	-	-	-
Collector–Emitter Saturation Voltage $(I_C = 4.0 \text{ mAdc}, I_B = 0.4 \text{ mAdc})$	V _{CE(sat)}	-	-	0.5	Vdc
Base-Emitter On Voltage (I _C = 4.0 mAdc, V _{CE} = 10 Vdc)	V _{BE}	-	-	0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product (I_C = 4.0 mAdc, V_{CE} = 10 Vdc, f = 100 MHz)	f _T	650	-	-	MHz
Collector-Base Capacitance $(V_{CB}= 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{cb}	-	-	0.7	pF
Common–Base Feedback Capacitance $(V_{CB}$ = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{rb}	-	-	0.65	pF
Collector Base Time Constant (I _C = 4.0 mAdc, V _{CB} = 10 Vdc, f = 31.8 MHz)	rb′C _c	-	-	9.0	ps

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



(V_{CB} = 10 Vdc, I_C = 4.0 mAdc, T_A = 25°C)

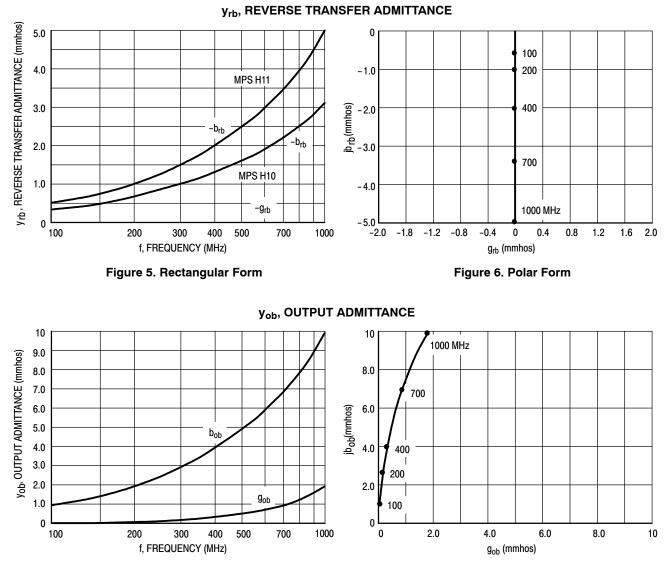
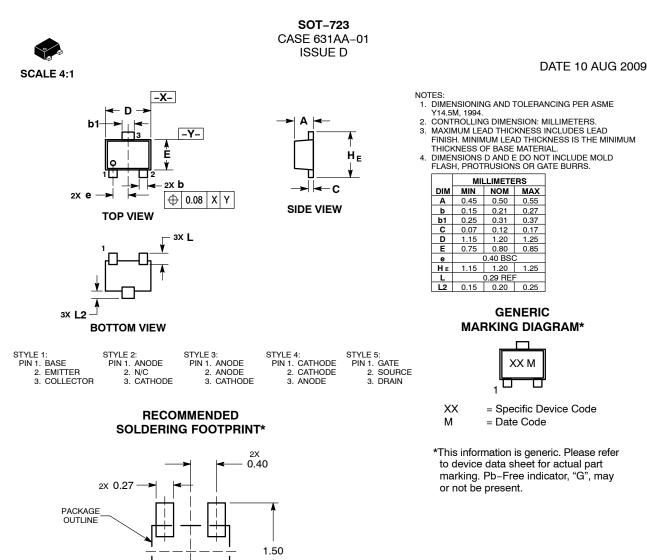


Figure 7. Rectangular Form

Figure 8. Polar Form





3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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 DESCRIPTION:
 SOT-723
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